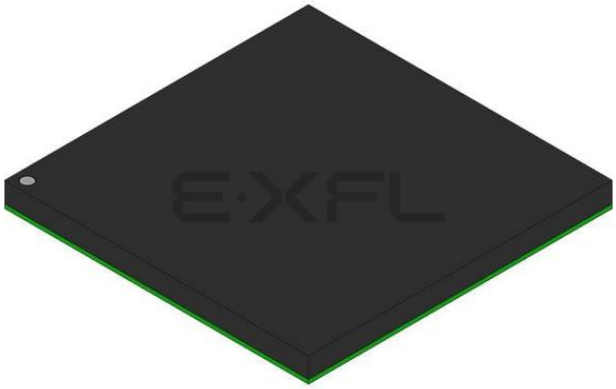

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Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of Embedded - Microprocessors

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details	
Product Status	Active
Core Processor	PowerPC e300c3
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	333MHz
Co-Processors/DSP	-
RAM Controllers	DDR, DDR2
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	10/100/1000Mbps (2)
SATA	-
USB	USB 2.0 + PHY (1)
Voltage - I/O	1.8V, 2.5V, 3.3V
Operating Temperature	-40°C ~ 105°C (TA)
Security Features	-
Package / Case	516-BBGA Exposed Pad
Supplier Device Package	516-TEPBGA (27x27)
Purchase URL	https://www.e-xfl.com/pro/item?MUrl=&PartUrl=mpc8313cvraffb

1.2 Serial Interfaces

The following interfaces are supported in the MPC8313E: dual UART, dual I^2C, and an SPI interface.

1.3 Security Engine

The security engine is optimized to handle all the algorithms associated with IPSec, IEEE Std 802.11i®, and iSCSI. The security engine contains one crypto-channel, a controller, and a set of crypto execution units (EUs). The execution units are as follows:

- Data encryption standard execution unit (DEU), supporting DES and 3DES
- Advanced encryption standard unit (AESU), supporting AES
- Message digest execution unit (MDEU), supporting MD5, SHA1, SHA-224, SHA-256, and HMAC with any algorithm
- One crypto-channel supporting multi-command descriptor chains

1.4 DDR Memory Controller

The MPC8313E DDR1/DDR2 memory controller includes the following features:

- Single 16- or 32-bit interface supporting both DDR1 and DDR2 SDRAM
- Support for up to 333 MHz
- Support for two physical banks (chip selects), each bank independently addressable
- 64-Mbit to 2-Gbit (for DDR1) and to 4-Gbit (for DDR2) devices with x8/x16/x32 data ports (no direct x4 support)
- Support for one 16-bit device or two 8-bit devices on a 16-bit bus, or one 32-bit device or two 16-bit devices on a 32-bit bus
- Support for up to 16 simultaneous open pages
- Supports auto refresh
- On-the-fly power management using CKE
- 1.8-/2.5-V SSTL2 compatible I/O

1.5 PCI Controller

The MPC8313E PCI controller includes the following features:

- PCI specification revision 2.3 compatible
- Single 32-bit data PCI interface operates at up to 66 MHz
- PCI 3.3-V compatible (not 5-V compatible)
- Support for host and agent modes
- On-chip arbitration, supporting three external masters on PCI
- Selectable hardware-enforced coherency

1.10 Serial Peripheral Interface (SPI)

The serial peripheral interface (SPI) allows the MPC8313E to exchange data between other PowerQUICC family chips, Ethernet PHYs for configuration, and peripheral devices such as EEPROMs, real-time clocks, A/D converters, and ISDN devices.

The SPI is a full-duplex, synchronous, character-oriented channel that supports a four-wire interface (receive, transmit, clock, and slave select). The SPI block consists of transmitter and receiver sections, an independent baud-rate generator, and a control unit.

1.11 DMA Controller, Dual I^2C, DUART, Local Bus Controller, and Timers

The MPC8313E provides an integrated four-channel DMA controller with the following features:

- Allows chaining (both extended and direct) through local memory-mapped chain descriptors (accessible by local masters)
- Supports misaligned transfers

There are two I^2C controllers. These synchronous, multi-master buses can be connected to additional devices for expansion and system development.

The DUART supports full-duplex operation and is compatible with the PC16450 and PC16550 programming models. The 16-byte FIFOs are supported for both the transmitter and the receiver.

The MPC8313E local bus controller (LBC) port allows connections with a wide variety of external DSPs and ASICs. Three separate state machines share the same external pins and can be programmed separately to access different types of devices. The general-purpose chip select machine (GPCM) controls accesses to asynchronous devices using a simple handshake protocol. The three user programmable machines (UPMs) can be programmed to interface to synchronous devices or custom ASIC interfaces. Each chip select can be configured so that the associated chip interface can be controlled by the GPCM or UPM controller. The FCM provides a glueless interface to parallel-bus NAND Flash E2PROM devices. The FCM contains three basic configuration register groups—BR*n*, OR*n*, and FMR. Both may exist in the same system. The local bus can operate at up to 66 MHz.

The MPC8313E system timers include the following features: periodic interrupt timer, real time clock, software watchdog timer, and two general-purpose timer blocks.

2 Electrical Characteristics

This section provides the AC and DC electrical specifications and thermal characteristics for the MPC8313E. The MPC8313E is currently targeted to these specifications. Some of these specifications are independent of the I/O cell, but are included for a more complete reference. These are not purely I/O buffer design specifications.

2.1 Overall DC Electrical Characteristics

This section covers the ratings, conditions, and other characteristics.

2.1.1 Absolute Maximum Ratings

This table provides the absolute maximum ratings.

Table 1. Absolute Maximum Ratings[1]

Characteristic		Symbol	Max Value	Unit	Note
Core supply voltage		V_{DD}	–0.3 to 1.26	V	—
PLL supply voltage		AV_{DD}	–0.3 to 1.26	V	—
Core power supply for SerDes transceivers		$XCOREV_{DD}$	–0.3 to 1.26	V	—
Pad power supply for SerDes transceivers		$XPADV_{DD}$	–0.3 to 1.26	V	—
DDR and DDR2 DRAM I/O voltage		GV_{DD}	–0.3 to 2.75 –0.3 to 1.98	V	—
PCI, local bus, DUART, system control and power management, I^2C, and JTAG I/O voltage		NV_{DD}/LV_{DD}	–0.3 to 3.6	V	—
eTSEC, USB		LV_{DDA}/LV_{DDB}	–0.3 to 3.6	V	—
Input voltage	DDR DRAM signals	MV_{IN}	–0.3 to (GV_{DD} + 0.3)	V	2, 5
	DDR DRAM reference	MV_{REF}	–0.3 to (GV_{DD} + 0.3)	V	2, 5
	Enhanced three-speed Ethernet signals	LV_{IN}	–0.3 to (LV_{DDA} + 0.3) or –0.3 to (LV_{DDB} + 0.3)	V	4, 5
	Local bus, DUART, SYS_CLK_IN, system control, and power management, I^2C, and JTAG signals	NV_{IN}	–0.3 to (NV_{DD} + 0.3)	V	3, 5
	PCI	NV_{IN}	–0.3 to (NV_{DD} + 0.3)	V	6
Storage temperature range		T_{STG}	–55 to 150	°C	—

Notes:

1. Functional and tested operating conditions are given in Table 2. Absolute maximum ratings are stress ratings only, and functional operation at the maximums is not guaranteed. Stresses beyond those listed may affect device reliability or cause permanent damage to the device.
2. **Caution:** MV_{IN} must not exceed GV_{DD} by more than 0.3 V. This limit may be exceeded for a maximum of 20 ms during power-on reset and power-down sequences.
3. **Caution:** NV_{IN} must not exceed NV_{DD} by more than 0.3 V. This limit may be exceeded for a maximum of 20 ms during power-on reset and power-down sequences.
4. **Caution:** LV_{IN} must not exceed LV_{DDA}/LV_{DDB} by more than 0.3 V. This limit may be exceeded for a maximum of 20 ms during power-on reset and power-down sequences.

2.1.2 Power Supply Voltage Specification

This table provides the recommended operating conditions for the MPC8313E. Note that the values in this table are the recommended and tested operating conditions. If a particular block is given a voltage falling within the range in the Recommended Value column, the MPC8313E is capable of delivering the amount of current listed in the Current Requirement column; this is the maximum current possible. Proper device operation outside of these conditions is not guaranteed.

Table 2. Recommended Operating Conditions

Characteristic	Symbol	Recommended Value[1]	Unit	Current Requirement
Core supply voltage	V_{DD}	1.0 V ± 50 mV	V	469 mA
Internal core logic constant power	V_{DDC}	1.0 V ± 50 mV	V	377 mA
SerDes internal digital power	$XCOREV_{DD}$	1.0	V	170 mA
SerDes internal digital ground	$XCOREV_{SS}$	0.0	V	—
SerDes I/O digital power	$XPADV_{DD}$	1.0	V	10 mA
SerDes I/O digital ground	$XPADV_{SS}$	0.0	V	—
SerDes analog power for PLL	$SDAV_{DD}$	1.0 V ± 50 mV	V	10 mA
SerDes analog ground for PLL	$SDAV_{SS}$	0.0	V	—
Dedicated 3.3 V analog power for USB PLL	USB_PLL_PWR3	3.3 V ± 300 mV	V	2–3 mA
Dedicated 1.0 V analog power for USB PLL	USB_PLL_PWR1	1.0 V ± 50 mV	V	2–3 mA
Dedicated analog ground for USB PLL	USB_PLL_GND	0.0	V	—
Dedicated USB power for USB bias circuit	USB_VDDA_BIAS	3.3 V ± 300 mV	V	4–5 mA
Dedicated USB ground for USB bias circuit	USB_VSSA_BIAS	0.0	V	—
Dedicated power for USB transceiver	USB_VDDA	3.3 V ± 300 mV	V	75 mA
Dedicated ground for USB transceiver	USB_VSSA	0.0	V	—
Analog power for e300 core APLL	AV_{DD1} [6]	1.0 V ± 50 mV	V	2–3 mA
Analog power for system APLL	AV_{DD2} [6]	1.0 V ± 50 mV	V	2–3 mA
DDR1 DRAM I/O voltage (333 MHz, 32-bit operation)	GV_{DD}	2.5 V ± 125 mV	V	131 mA
DDR2 DRAM I/O voltage (333 MHz, 32-bit operation)	GV_{DD}	1.8 V ± 80 mV	V	140 mA
Differential reference voltage for DDR controller	MV_{REF}	1/2 DDR supply ($0.49 \times GV_{DD}$ to $0.51 \times GV_{DD}$)	V	—
Standard I/O voltage	NV_{DD}	3.3 V ± 300 mV[2]	V	74 mA
eTSEC2 I/O supply	LV_{DDA}	2.5 V ± 125 mV/ 3.3 V ± 300 mV	V	22 mA
eTSEC1/USB DR I/O supply	LV_{DDB}	2.5 V ± 125 mV/ 3.3 V ± 300 mV	V	44 mA
Supply for eLBC IOs	LV_{DD}	3.3 V ± 300 mV	V	16 mA
Analog and digital ground	V_{SS}	0.0	V	—
Junction temperature range	T_A/T_J [3]	0 to 105	°C	

This figure shows the RGMII and RTBI AC timing and multiplexing diagrams.

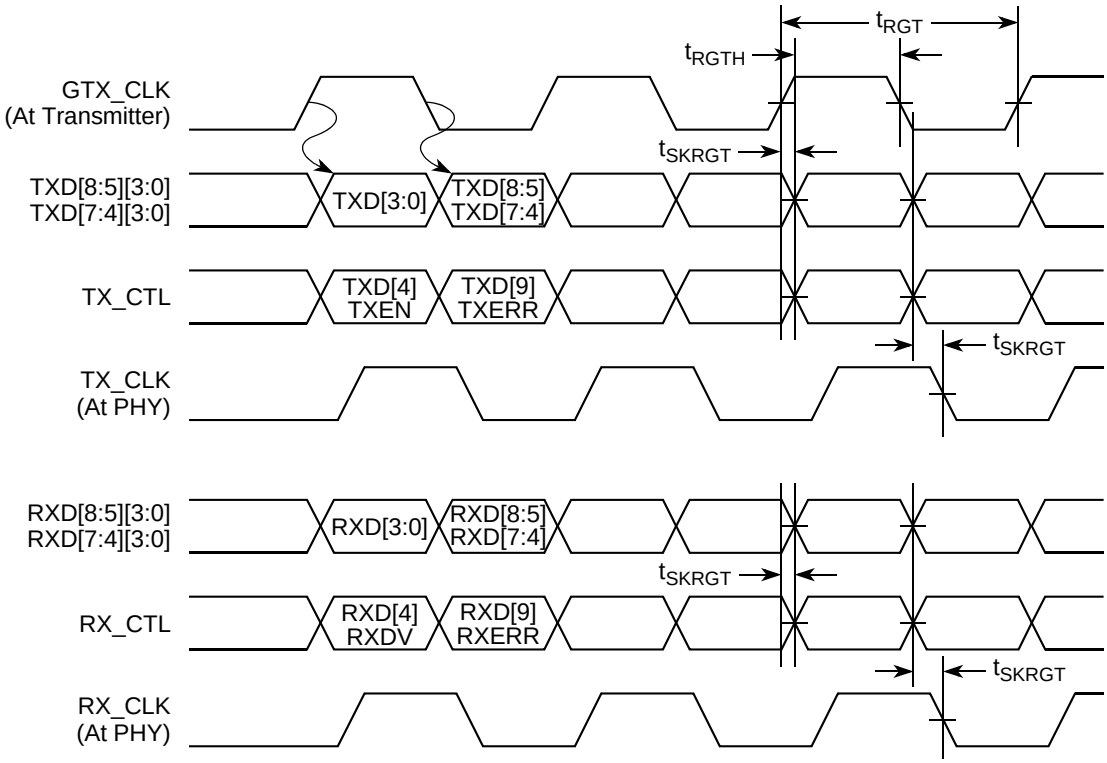


Figure 14. RGMII and RTBI AC Timing and Multiplexing Diagrams

8.3 SGMII Interface Electrical Characteristics

Each SGMII port features a 4-wire AC-coupled serial link from the dedicated SerDes interface of MPC8313E as shown in Figure 15, where C_{TX} is the external (on board) AC-coupled capacitor. Each output pin of the SerDes transmitter differential pair features a 50-Ω output impedance. Each input of the SerDes receiver differential pair features 50-Ω on-die termination to XCOREVSS. The reference circuit of the SerDes transmitter and receiver is shown in Figure 33.

When an eTSEC port is configured to operate in SGMII mode, the parallel interface's output signals of this eTSEC port can be left floating. The input signals should be terminated based on the guidelines described in Section 22.5, "Connection Recommendations," as long as such termination does not violate the desired POR configuration requirement on these pins, if applicable.

When operating in SGMII mode, the TSEC_GTX_CLK125 clock is not required for this port. Instead, the SerDes reference clock is required on SD_REF_CLK and $\overline{\text{SD\_REF\_CLK}}$ pins.

8.3.1 DC Requirements for SGMII SD_REF_CLK and $\overline{\text{SD\_REF\_CLK}}$

The characteristics and DC requirements of the separate SerDes reference clock are described in Section 9, "High-Speed Serial Interfaces (HSSI)."

Table 35. SGMII Receive AC Timing Specifications (continued)

At recommended operating conditions with $XCOREV_{DD}$ = 1.0 V ± 5%.

Parameter	Symbol	Min	Typ	Max	Unit	Note
Total jitter tolerance	JT	0.65	—	—	UI p-p	1
Bit error ratio	BER	—	—	10^{-12}		
Unit interval	UI	799.92	800	800.08	ps	2
AC coupling capacitor	C_{TX}	5	—	200	nF	3

Notes:
1. Measured at receiver.
2. Each UI is 800 ps ± 100 ppm.
3. The external AC coupling capacitor is required. It is recommended to be placed near the device transmitter outputs.

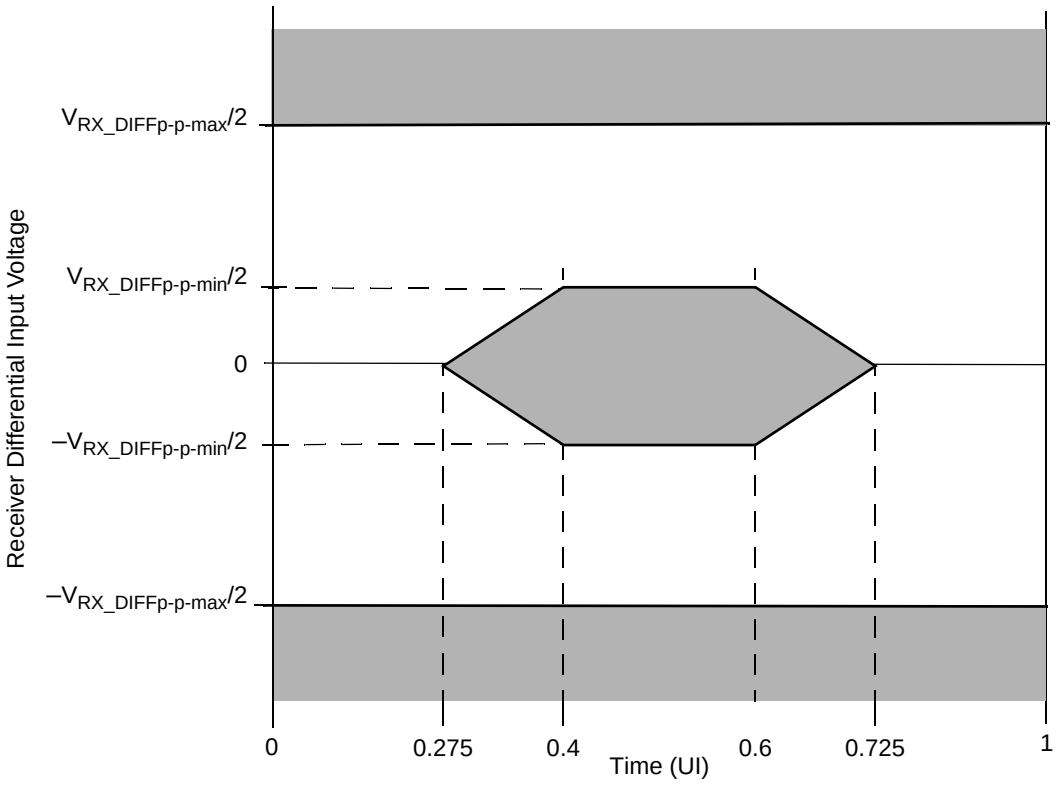


Figure 17. SGMII Receiver Input Compliance Mask

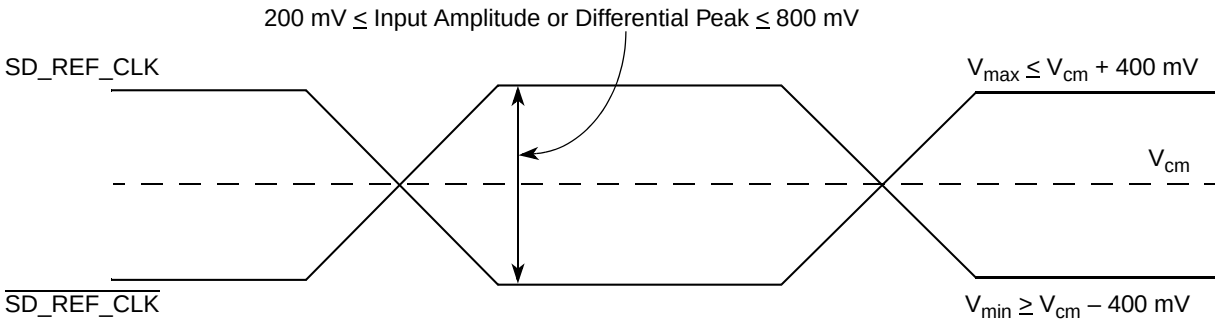


Figure 25. Differential Reference Clock Input DC Requirements (External AC-Coupled)

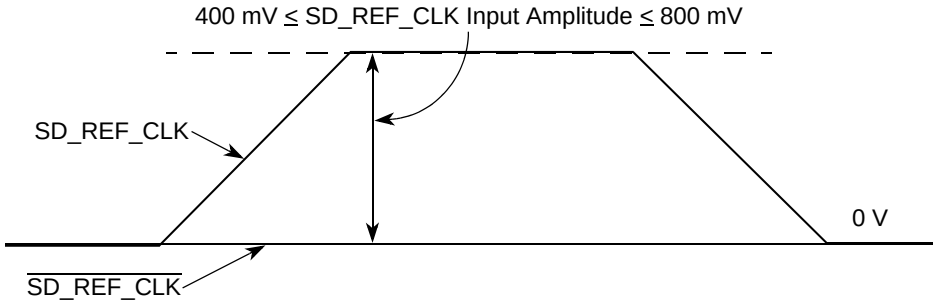


Figure 26. Single-Ended Reference Clock Input DC Requirements

9.2.3 Interfacing With Other Differential Signaling Levels

- With on-chip termination to $XCOREV_{SS}$, the differential reference clocks inputs are HCSL (high-speed current steering logic) compatible DC coupled.
- Many other low voltage differential type outputs like LVDS (low voltage differential signaling) can be used but may need to be AC coupled due to the limited common mode input range allowed (100 to 400 mV) for DC-coupled connection.
- LVPECL outputs can produce a signal with too large of an amplitude and may need to be DC-biased at the clock driver output first, then followed with series attenuation resistor to reduce the amplitude, in addition to AC coupling.

NOTE

Figure 27 through Figure 30 are for conceptual reference only. Due to the fact that the clock driver chip's internal structure, output impedance, and termination requirements are different between various clock driver chip manufacturers, it is possible that the clock circuit reference designs provided by clock driver chip vendors are different from what is shown in the figures. They might also vary from one vendor to the other. Therefore, Freescale can neither provide the optimal clock driver reference circuits, nor guarantee the correctness of the following clock driver connection reference circuits. It is recommended that the system designer contact the selected clock driver chip vendor for the optimal reference circuits for the MPC8313E SerDes reference clock receiver requirement provided in this document.

assumes that the LVPECL clock driver's output impedance is 50 Ω. R1 is used to DC-bias the LVPECL outputs prior to AC coupling. Its value could be ranged from 140 to 240 Ω depending on the clock driver vendor's requirement. R2 is used together with the SerDes reference clock receiver's 50-Ω termination resistor to attenuate the LVPECL output's differential peak level such that it meets the MPC8313E SerDes3 reference clock's differential input amplitude requirement (between 200 and 800 mV differential peak). For example, if the LVPECL output's differential peak is 900 mV and the desired SerDes reference clock input amplitude is selected as 600 mV, the attenuation factor is 0.67, which requires R2 = 25 Ω. Consult with the clock driver chip manufacturer to verify whether this connection scheme is compatible with a particular clock driver chip.

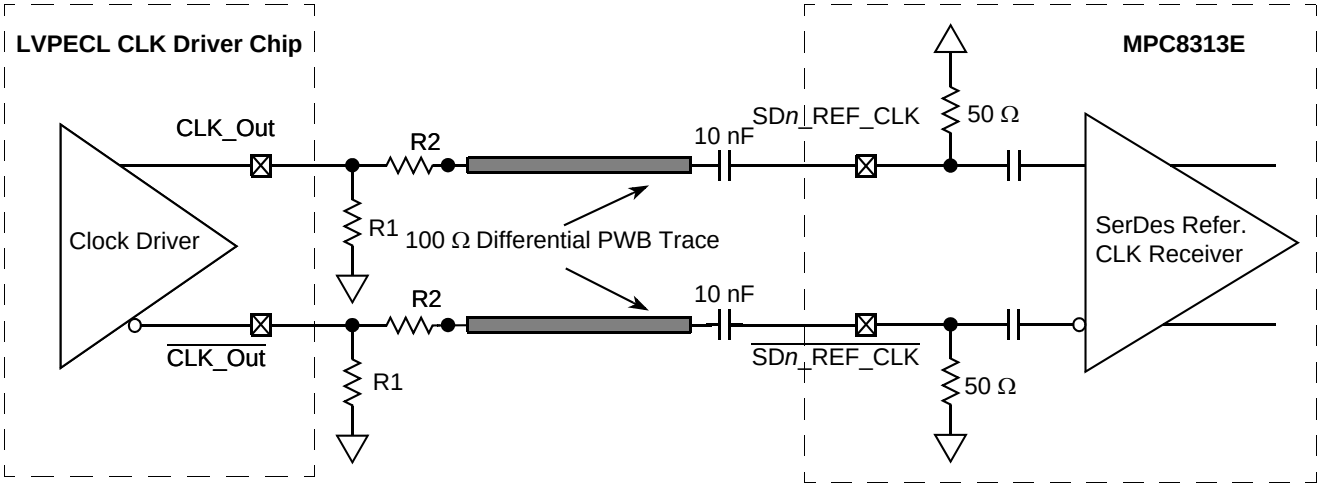


Figure 29. AC-Coupled Differential Connection with LVPECL Clock Driver (Reference Only)

This figure shows the SerDes reference clock connection reference circuits for a single-ended clock driver. It assumes the DC levels of the clock driver are compatible with the MPC8313E SerDes reference clock input's DC requirement.

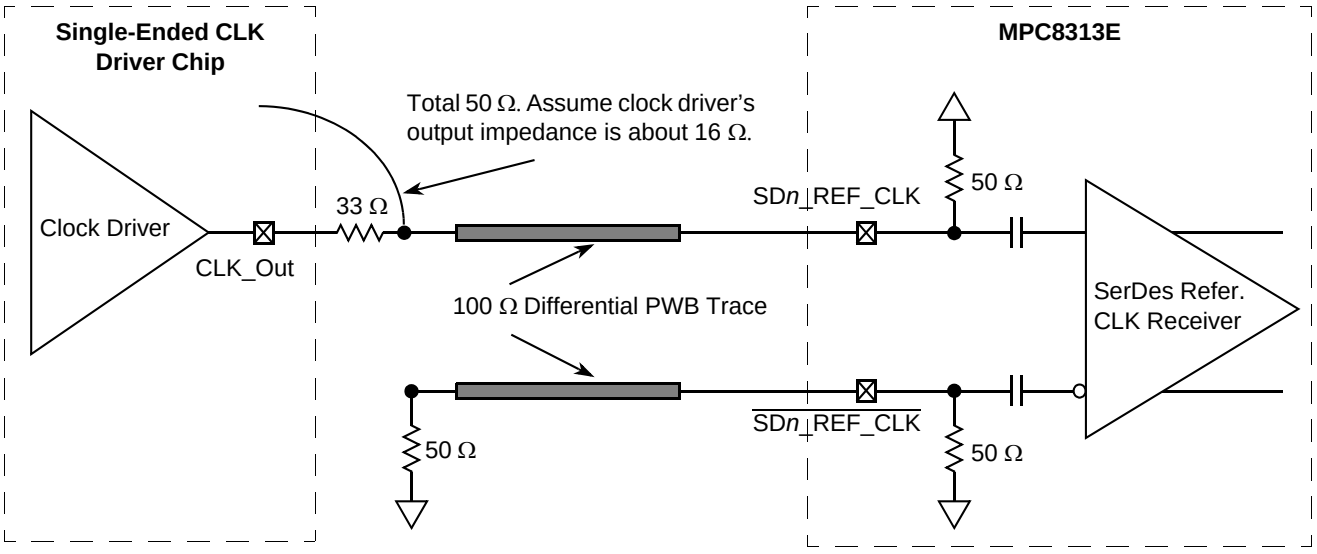


Figure 30. Single-Ended Connection (Reference Only)

9.2.4 AC Requirements for SerDes Reference Clocks

The clock driver selected should provide a high quality reference clock with low-phase noise and cycle-to-cycle jitter. Phase noise less than 100 kHz can be tracked by the PLL and data recovery loops and is less of a problem. Phase noise above 15 MHz is filtered by the PLL. The most problematic phase noise occurs in the 1–15 MHz range. The source impedance of the clock driver should be 50 Ω to match the transmission line and reduce reflections which are a source of noise to the system.

This table describes some AC parameters for SGMII protocol.

Table 39. SerDes Reference Clock Common AC Parameters

At recommended operating conditions with XV_{DD_SRDS1} or XV_{DD_SRDS2} = 1.0 V ± 5%.

Parameter	Symbol	Min	Max	Unit	Note
Rising edge rate	Rise edge rate	1.0	4.0	V/ns	2, 3
Falling edge rate	Fall edge rate	1.0	4.0	V/ns	2, 3
Differential input high voltage	V_{IH}	+200	—	mV	2
Differential input low voltage	V_{IL}	—	–200	mV	2
Rising edge rate (SDn_REF_CLK) to falling edge rate ($\overline{\text{SDn\_REF\_CLK}}$) matching	Rise-fall matching	—	20	%	1, 4

Notes:
1. Measurement taken from single-ended waveform.
2. Measurement taken from differential waveform.
3. Measured from –200 to +200 mV on the differential waveform (derived from SD*n*_REF_CLK minus $\overline{\text{SD}n\text{\_REF\_CLK}}$). The signal must be monotonic through the measurement region for rise and fall time. The 400 mV measurement window is centered on the differential zero crossing. See Figure 31.
4. Matching applies to rising edge rate for SD*n*_REF_CLK and falling edge rate for $\overline{\text{SD}n\text{\_REF\_CLK}}$. It is measured using a 200 mV window centered on the median cross point, where SD*n*_REF_CLK rising meets $\overline{\text{SD}n\text{\_REF\_CLK}}$ falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations. The rise edge rate of SD*n*_REF_CLK should be compared to the fall edge rate of $\overline{\text{SD}n\text{\_REF\_CLK}}$, the maximum allowed difference should not exceed 20% of the slowest edge rate. See Figure 32.

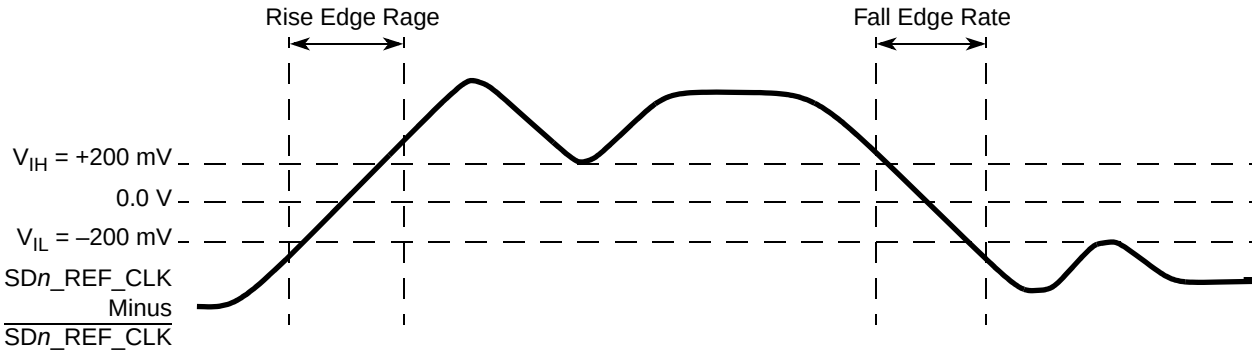


Figure 31. Differential Measurement Points for Rise and Fall Time

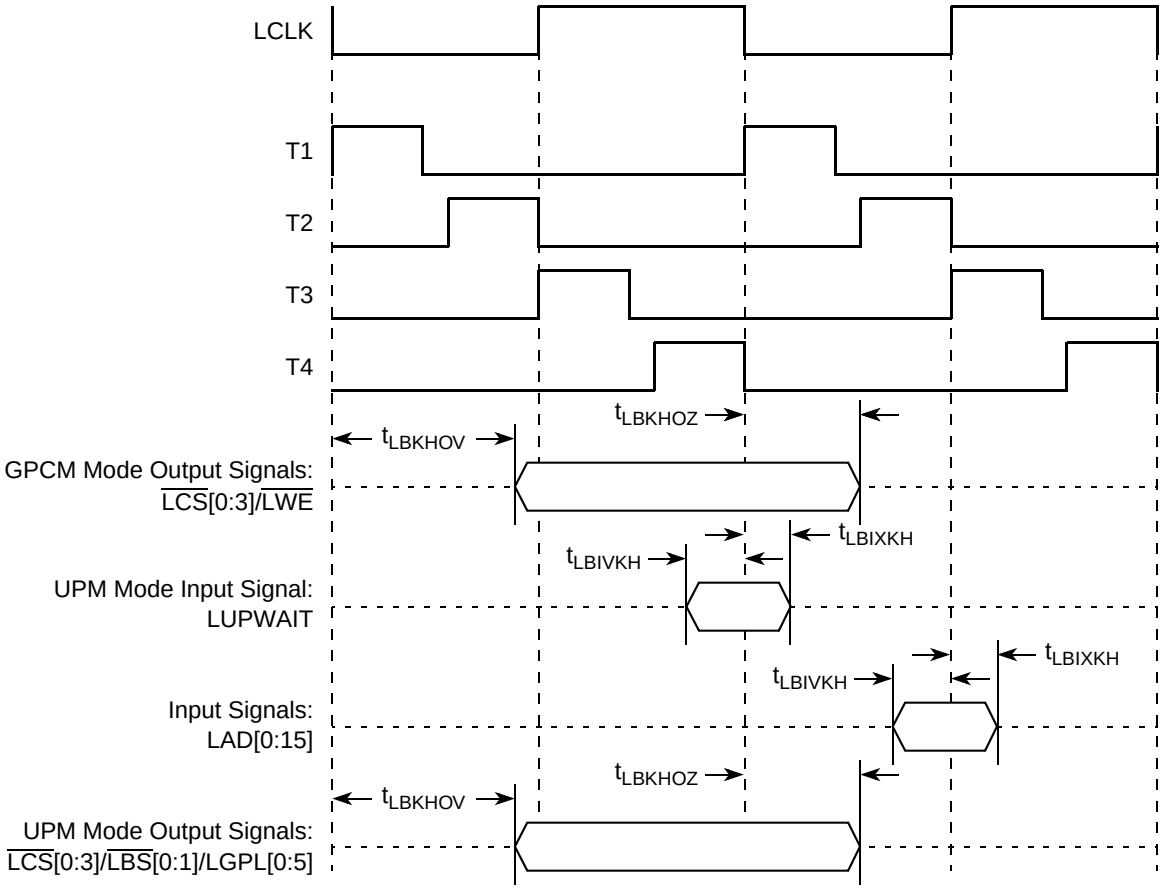


Figure 39. Local Bus Signals, GPCM/UPM Signals for LCRR[CLKDIV] = 4

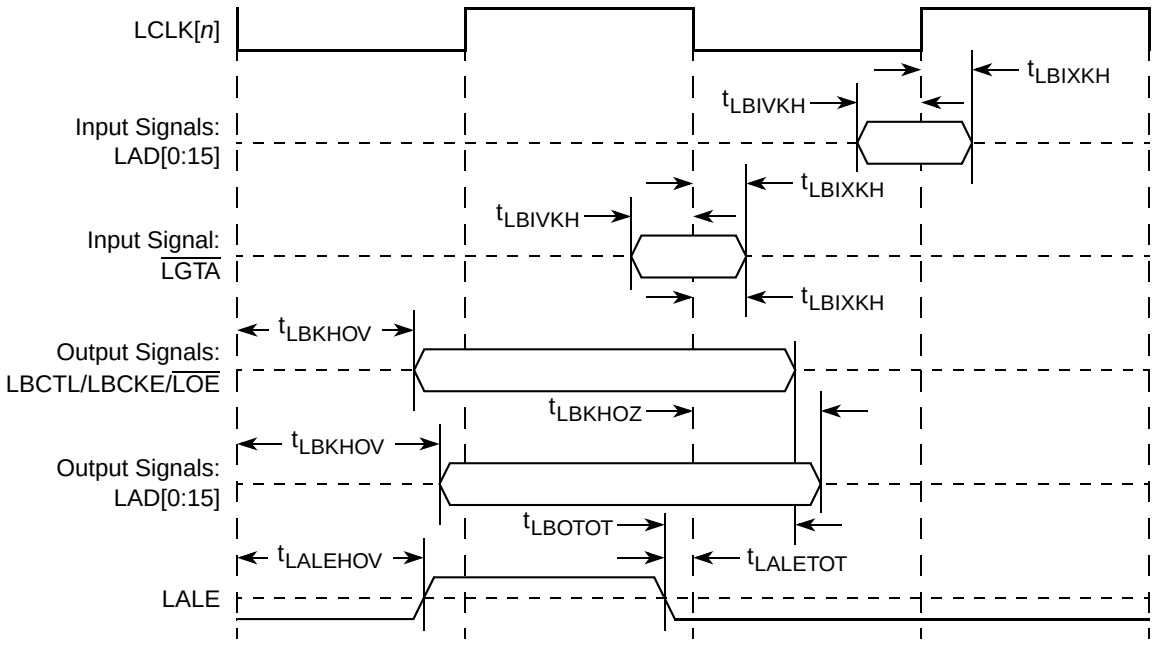


Figure 40. Local Bus Signals, LALE with Respect to LCLK

Table 49. I²C AC Electrical Specifications (continued)

All values refer to V_{IH} (min) and V_{IL} (max) levels (see Table 48).

Parameter	Symbol[1]	Min	Max	Unit
Data hold time: CBUS compatible masters I²C bus devices	t_{I2DXKL}	 — 0[2]	 — 0.9[3]	µs
Fall time of both SDA and SCL signals[5]	t_{I2CF}	—	300	ns
Setup time for STOP condition	t_{I2PVKH}	0.6	—	µs
Bus free time between a STOP and START condition	t_{I2KHDX}	1.3	—	µs
Noise margin at the LOW level for each connected device (including hysteresis)	V_{NL}	$0.1 \times NV_{DD}$	—	V
Noise margin at the HIGH level for each connected device (including hysteresis)	V_{NH}	$0.2 \times NV_{DD}$	—	V

Notes:

1. The symbols used for timing specifications follow the pattern of $t_{\text{(first two letters of functional block)(signal)(state)(reference)(state)}}$ for inputs and $t_{\text{(first two letters of functional block)(reference)(state)(signal)(state)}}$ for outputs. For example, t_{I2DVKH} symbolizes I²C timing (I2) with respect to the time data input signals (D) reach the valid state (V) relative to the t_{I2C} clock reference (K) going to the high (H) state or setup time. Also, t_{I2SXKL} symbolizes I²C timing (I2) for the time that the data with respect to the start condition (S) went invalid (X) relative to the t_{I2C} clock reference (K) going to the low (L) state or hold time. Also, t_{I2PVKH} symbolizes I²C timing (I2) for the time that the data with respect to the stop condition (P) reaching the valid state (V) relative to the t_{I2C} clock reference (K) going to the high (H) state or setup time. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).
2. The MPC8313E provides a hold time of at least 300 ns for the SDA signal (referred to the V_{IHmin} of the SCL signal) to bridge the undefined region of the falling edge of SCL.
3. The maximum t_{I2DVKH} has only to be met if the device does not stretch the LOW period (t_{I2CL}) of the SCL signal.
4. C_B = capacitance of one bus line in pF.
5. The MPC8313E does not follow the *I²C-BUS Specifications, Version 2.1,* regarding the t_{I2CF} AC parameter.

This figure provides the AC test load for the I²C.

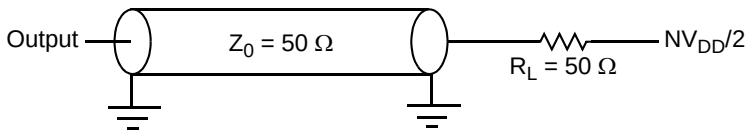
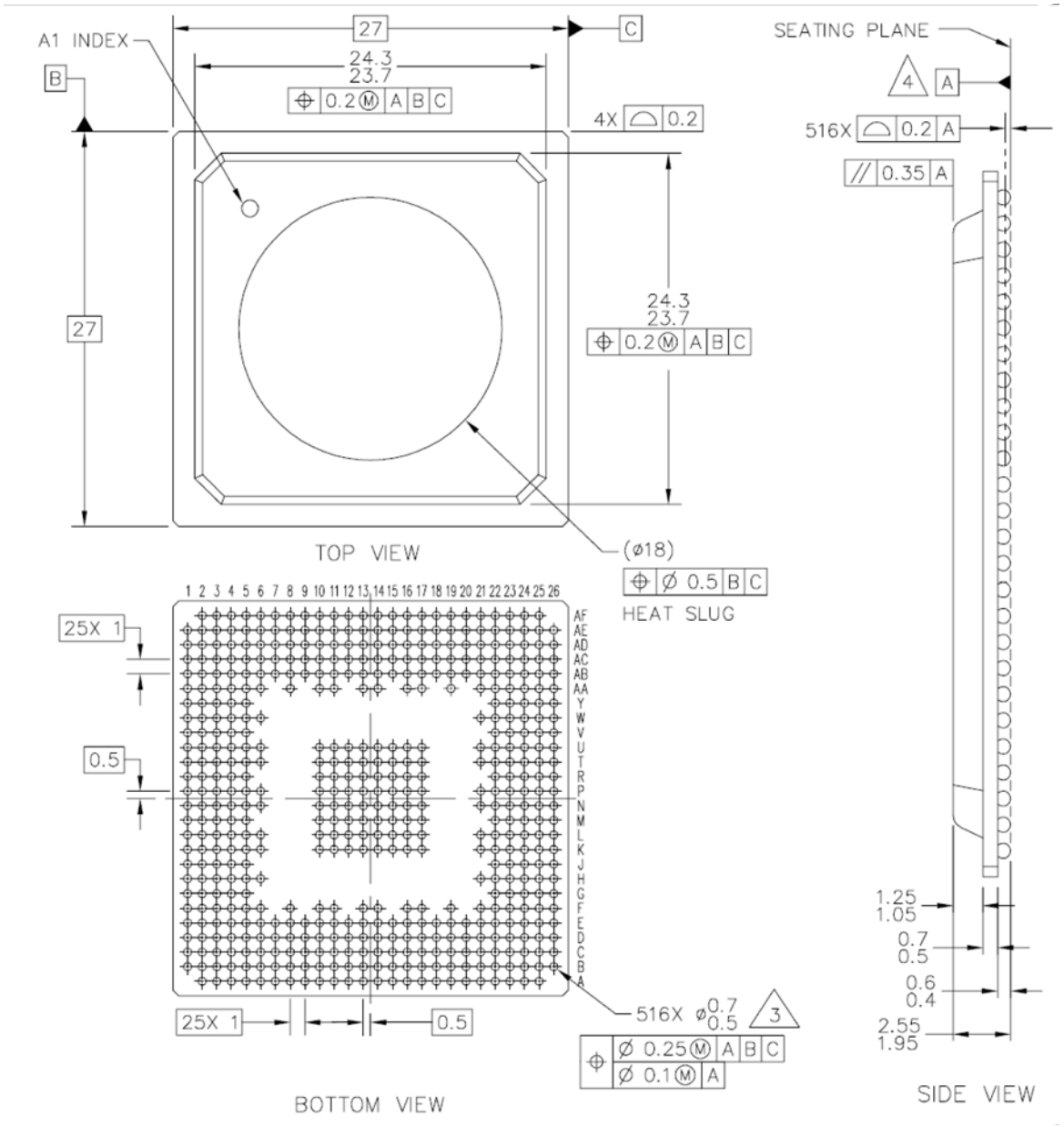


Figure 46. I²C AC Test Load

19.2 Mechanical Dimensions of the MPC8313E TEPBGAII

This figure shows the mechanical dimensions and bottom surface nomenclature of the 516-TEPBGAII package.



Notes:
1. All dimensions are in millimeters.
2. Dimensions and tolerances per ASME Y14.5M-1994.
3. Maximum solder ball diameter measured parallel to datum A.
4. Datum A, the seating plane, is determined by the spherical crowns of the solder balls.
5. Package code 5368 is to account for PGE and the built-in heat spreader.

Figure 56. Mechanical Dimension and Bottom Surface Nomenclature of the MPC8313E TEPBGAII

19.3 Pinout Listings

This table provides the pin-out listing for the MPC8313E, TEPBGAII package.

Table 62. MPC8313E TEPBGAII Pinout Listing

Signal	Package Pin Number	Pin Type	Power Supply	Note
DDR Memory Controller Interface				
MEMC_MDQ0	A8	I/O	GV_{DD}	—
MEMC_MDQ1	A9	I/O	GV_{DD}	—
MEMC_MDQ2	C10	I/O	GV_{DD}	—
MEMC_MDQ3	C9	I/O	GV_{DD}	—
MEMC_MDQ4	E9	I/O	GV_{DD}	—
MEMC_MDQ5	E11	I/O	GV_{DD}	—
MEMC_MDQ6	E10	I/O	GV_{DD}	—
MEMC_MDQ7	C8	I/O	GV_{DD}	—
MEMC_MDQ8	E8	I/O	GV_{DD}	—
MEMC_MDQ9	A6	I/O	GV_{DD}	—
MEMC_MDQ10	B6	I/O	GV_{DD}	—
MEMC_MDQ11	C6	I/O	GV_{DD}	—
MEMC_MDQ12	C7	I/O	GV_{DD}	—
MEMC_MDQ13	D7	I/O	GV_{DD}	—
MEMC_MDQ14	D6	I/O	GV_{DD}	—
MEMC_MDQ15	A5	I/O	GV_{DD}	—
MEMC_MDQ16	A19	I/O	GV_{DD}	—
MEMC_MDQ17	D18	I/O	GV_{DD}	—
MEMC_MDQ18	A17	I/O	GV_{DD}	—
MEMC_MDQ19	E17	I/O	GV_{DD}	—
MEMC_MDQ20	E16	I/O	GV_{DD}	—
MEMC_MDQ21	C18	I/O	GV_{DD}	—
MEMC_MDQ22	D19	I/O	GV_{DD}	—
MEMC_MDQ23	C19	I/O	GV_{DD}	—
MEMC_MDQ24	E19	I/O	GV_{DD}	—
MEMC_MDQ25	A22	I/O	GV_{DD}	—
MEMC_MDQ26	C21	I/O	GV_{DD}	—
MEMC_MDQ27	C20	I/O	GV_{DD}	—
MEMC_MDQ28	A21	I/O	GV_{DD}	—

Table 62. MPC8313E TEPBGAII Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Note
LA24	E23	O	LV_{DD}	11
LA25	D22	O	LV_{DD}	11
$\overline{\text{LCS0}}$	D23	O	LV_{DD}	10
$\overline{\text{LCS1}}$	J26	O	LV_{DD}	10
$\overline{\text{LCS2}}$	F22	O	LV_{DD}	10
$\overline{\text{LCS3}}$	D26	O	LV_{DD}	10
$\overline{\text{LWE0}}$/$\overline{\text{LFWE}}$	E24	O	LV_{DD}	10
$\overline{\text{LWE1}}$	H26	O	LV_{DD}	10
LBCTL	L22	O	LV_{DD}	10
LALE/M1LALE/M2LALE	E26	O	LV_{DD}	11
LGPL0/LFCLE	AA23	O	LV_{DD}	—
LGPL1/LFALE	AA24	O	LV_{DD}	—
LGPL2/$\overline{\text{LOE}}$/$\overline{\text{LFRE}}$	AA25	O	LV_{DD}	10
LGPL3/$\overline{\text{LFWP}}$	AA26	O	LV_{DD}	—
LGPL4/$\overline{\text{LGTA}}$/LUPWAIT/$\overline{\text{LFRB}}$	Y22	I/O	LV_{DD}	2
LGPL5	E21	O	LV_{DD}	10
LCLK0	H22	O	LV_{DD}	11
LCLK1	G26	O	LV_{DD}	11
LA0/GPIO0/MSRCID0	AC24	I/O	LV_{DD}	—
LA1/GPIO1//MSRCID1	Y24	I/O	LV_{DD}	—
LA2/GPIO2//MSRCID2	Y26	I/O	LV_{DD}	—
LA3/GPIO3//MSRCID3	W22	I/O	LV_{DD}	—
LA4/GPIO4//MSRCID4	W24	I/O	LV_{DD}	—
LA5/GPIO5/MDVAL	W26	I/O	LV_{DD}	—
LA6/GPIO6	V22	I/O	LV_{DD}	—
LA7/GPIO7/TSEC_1588_TRIG2	V23	I/O	LV_{DD}	8
LA8/GPIO13/TSEC_1588_ALARM1	V24	I/O	LV_{DD}	8
LA9/GPIO14/TSEC_1588_PP3	V25	I/O	LV_{DD}	8
LA10/TSEC_1588_CLK	V26	O	LV_{DD}	8
LA11/TSEC_1588_GCLK	U22	O	LV_{DD}	8
LA12/TSEC_1588_PP1	AD24	O	LV_{DD}	8
LA13/TSEC_1588_PP2	L25	O	LV_{DD}	8

Table 62. MPC8313E TEPBGAII Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Note
LA14/TSEC_1588_TRIG1	L24	O	LV_{DD}	8
LA15/TSEC_1588_ALARM2	K26	O	LV_{DD}	8
DUART				
UART_SOUT1/MSRCID0	N2	O	NV_{DD}	—
UART_SIN1/MSRCID1	M5	I/O	NV_{DD}	—
$\overline{\text{UART\_CTS1}}$/GPIO8/MSRCID2	M1	I/O	NV_{DD}	—
$\overline{\text{UART\_RTS1}}$/GPIO9/MSRCID3	K1	I/O	NV_{DD}	—
UART_SOUT2/MSRCID4/TSEC_1588_CLK	M3	O	NV_{DD}	8
UART_SIN2/MDVAL/TSEC_1588_GCLK	L1	I/O	NV_{DD}	8
$\overline{\text{UART\_CTS2}}$/TSEC_1588_PP1	L5	I/O	NV_{DD}	8
$\overline{\text{UART\_RTS2}}$/TSEC_1588_PP2	L3	I/O	NV_{DD}	8
I^2C interface				
IIC1_SDA/$\overline{\text{CKSTOP\_OUT}}$/TSEC_1588_TRIG1	J4	I/O	NV_{DD}	2, 8
IIC1_SCL/$\overline{\text{CKSTOP\_IN}}$/TSEC_1588_ALARM2	J2	I/O	NV_{DD}	2, 8
IIC2_SDA/PMC_PWR_OK/GPIO10	J3	I/O	NV_{DD}	2
IIC2_SCL/GPIO11	H5	I/O	NV_{DD}	2
Interrupts				
$\overline{\text{MCP\_OUT}}$	G5	O	NV_{DD}	2
$\overline{\text{IRQ0}}$/$\overline{\text{MCP\_IN}}$	K5	I	NV_{DD}	—
$\overline{\text{IRQ1}}$	K4	I	NV_{DD}	—
$\overline{\text{IRQ2}}$	K2	I	NV_{DD}	—
$\overline{\text{IRQ3}}$/$\overline{\text{CKSTOP\_OUT}}$	K3	I/O	NV_{DD}	—
$\overline{\text{IRQ4}}$/$\overline{\text{CKSTOP\_IN}}$/GPIO12	J1	I/O	NV_{DD}	—
Configuration				
$\overline{\text{CFG\_CLKIN\_DIV}}$	D5	I	NV_{DD}	—
EXT_PWR_CTRL	J5	O	NV_{DD}	—
CFG_LBIU_MUX_EN	R24	I	NV_{DD}	—
JTAG				
TCK	E1	I	NV_{DD}	—
TDI	E2	I	NV_{DD}	4
TDO	E3	O	NV_{DD}	3

20.2 Core PLL Configuration

RCWL[COREPLL] selects the ratio between the internal coherent system bus clock (*csb_clk*) and the e300 core clock (*core_clk*). This table shows the encodings for RCWL[COREPLL]. COREPLL values that are not listed in this table should be considered as reserved.

NOTE

Core VCO frequency = core frequency × VCO divider. The VCO divider, which is determined by RCWLR[COREPLL], must be set properly so that the core VCO frequency is in the range of 400–800 MHz.

Table 67. e300 Core PLL Configuration

RCWL[COREPLL]			***core_clk* : *csb_clk* Ratio**[1]	**VCO Divider (VCOD)**[3]
0–1	**2–5**	**6**		
nn	**0000**	0	PLL bypassed (PLL off, *csb_clk* clocks core directly)	PLL bypassed (PLL off, *csb_clk* clocks core directly)
11	***nnnn***	n	n/a	n/a
00	**0001**	0	1:1	2
01	**0001**	0	1:1	4
10	**0001**	0	1:1	8
00	**0001**	1	1.5:1	2
01	**0001**	1	1.5:1	4
10	**0001**	1	1.5:1	8
00	**0010**	0	2:1	2
01	**0010**	0	2:1	4
10	**0010**	0	2:1	8
00	**0010**	1	2.5:1	2
01	**0010**	1	2.5:1	4
10	**0010**	1	2.5:1	8
00	**0011**	0	3:1	2
01	**0011**	0	3:1	4
10	**0011**	0	3:1	8

Note:

1. For *core_clk:csb_clk* ratios of 2.5:1 and 3:1, the *core_clk* must not exceed its maximum operating frequency of 333 MHz.
2. Core VCO frequency = core frequency × VCO divider. Note that VCO divider has to be set properly so that the core VCO frequency is in the range of 400–800 MHz.

21.3 Heat Sink Attachment

When attaching heat sinks to these devices, an interface material is required. The best method is to use thermal grease and a spring clip. The spring clip should connect to the printed-circuit board, either to the board itself, to hooks soldered to the board, or to a plastic stiffener. Avoid attachment forces which would lift the edge of the package or peel the package from the board. Such peeling forces reduce the solder joint lifetime of the package. Recommended maximum force on the top of the package is 10 lb (4.5 kg) force. If an adhesive attachment is planned, the adhesive should be intended for attachment to painted or plastic surfaces and its performance verified under the application requirements.

21.3.1 Experimental Determination of the Junction Temperature with a Heat Sink

When heat sink is used, the junction temperature is determined from a thermocouple inserted at the interface between the case of the package and the interface material. A clearance slot or hole is normally required in the heat sink. Minimizing the size of the clearance is important to minimize the change in thermal performance caused by removing part of the thermal interface to the heat sink. Because of the experimental difficulties with this technique, many engineers measure the heat sink temperature and then back calculate the case temperature using a separate measurement of the thermal resistance of the interface. From this case temperature, the junction temperature is determined from the junction to case thermal resistance.

$$T_J = T_C + (R_{\theta JC} \times P_D)$$

where:

T_J = junction temperature (°C)
T_C = case temperature of the package
$R_{\theta JC}$ = junction-to-case thermal resistance
P_D = power dissipation

22 System Design Information

This section provides electrical and thermal design recommendations for successful application of the MPC8313E SYS_CLK_IN

22.1 System Clocking

The MPC8313E includes three PLLs.

1. The platform PLL (AV_{DD2}) generates the platform clock from the externally supplied SYS_CLK_IN input in PCI host mode or SYS_CLK_IN/PCI_SYNC_IN in PCI agent mode. The frequency ratio between the platform and SYS_CLK_IN is selected using the platform PLL ratio configuration bits as described in Section 20.1, “System PLL Configuration.”
2. The e300 core PLL (AV_{DD1}) generates the core clock as a slave to the platform clock. The frequency ratio between the e300 core clock and the platform clock is selected using the e300 PLL ratio configuration bits as described in Section 20.2, “Core PLL Configuration.”
3. There is a PLL for the SerDes block.

- Third, between the device and any SerDes voltage regulator there should be a 10-µF, low equivalent series resistance (ESR) SMT tantalum chip capacitor and a 100-µF, low ESR SMT tantalum chip capacitor. This should be done for all SerDes supplies.

22.5 Connection Recommendations

To ensure reliable operation, it is highly recommended to connect unused inputs to an appropriate signal level. Unused active low inputs should be tied to NV_{DD}, GV_{DD}, LV_{DD}, LV_{DDA}, or LV_{DDB} as required. Unused active high inputs should be connected to V_{SS}. All NC (no-connect) signals must remain unconnected.

Power and ground connections must be made to all external V_{DD}, NV_{DD}, GV_{DD}, LV_{DD}, LV_{DDA}, LV_{DDB}, and V_{SS} pins of the device.

22.6 Output Buffer DC Impedance

The MPC8313E drivers are characterized over process, voltage, and temperature. For all buses, the driver is a push-pull single-ended driver type (open drain for I^2C).

To measure Z_0 for the single-ended drivers, an external resistor is connected from the chip pad to NV_{DD} or V_{SS}. Then, the value of each resistor is varied until the pad voltage is $NV_{DD}/2$ (see Figure 60). The output impedance is the average of two components, the resistances of the pull-up and pull-down devices. When data is held high, SW1 is closed (SW2 is open), and R_P is trimmed until the voltage at the pad equals $NV_{DD}/2$. R_P then becomes the resistance of the pull-up devices. R_P and R_N are designed to be close to each other in value. Then, $Z_0 = (R_P + R_N)/2$.

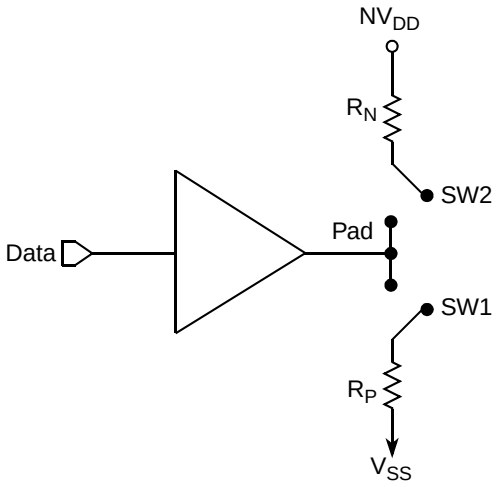


Figure 60. Driver Impedance Measurement

The value of this resistance and the strength of the driver's current source can be found by making two measurements. First, the output voltage is measured while driving logic 1 without an external differential termination resistor. The measured voltage is $V_1 = R_{source} \times I_{source}$. Second, the output voltage is measured while driving logic 1 with an external precision differential termination resistor of value R_{term}. The measured voltage is $V_2 = (1/(1/R_1 + 1/R_2)) \times I_{source}$. Solving for the output impedance gives $R_{source} = R_{term} \times (V_1/V_2 - 1)$. The drive current is then $I_{source} = V_1/R_{source}$.

This table summarizes the signal impedance targets. The driver impedance are targeted at minimum V_{DD}, nominal NV_{DD}, 105°C.

Table 71. Impedance Characteristics

Impedance	Local Bus, Ethernet, DUART, Control, Configuration, Power Management	PCI Signals (Not Including PCI Output Clocks)	PCI Output Clocks (Including PCI_SYNC_OUT)	DDR DRAM	Symbol	Unit
R_N	42 Target	25 Target	42 Target	20 Target	Z_0	Ω
R_P	42 Target	25 Target	42 Target	20 Target	Z_0	Ω
Differential	NA	NA	NA	NA	Z_{DIFF}	Ω

Note: Nominal supply voltages. See Table 1, T_J = 105 °C.

22.7 Configuration Pin Muxing

The MPC8313E provides the user with power-on configuration options which can be set through the use of external pull-up or pull-down resistors of 4.7 kΩ on certain output pins (see customer visible configuration pins). These pins are generally used as output only pins in normal operation.

While $\overline{\text{HRESET}}$ is asserted however, these pins are treated as inputs. The value presented on these pins while $\overline{\text{HRESET}}$ is asserted, is latched when $\overline{\text{PORESET}}$ deasserts, at which time the input receiver is disabled and the I/O circuit takes on its normal function. Careful board layout with stubless connections to these pull-up/pull-down resistors coupled with the large value of the pull-up/pull-down resistor should minimize the disruption of signal quality or speed for output pins thus configured.

22.8 Pull-Up Resistor Requirements

The MPC8313E requires high resistance pull-up resistors (10 kΩ is recommended) on open drain type pins including I^2C, and IPIC (integrated programmable interrupt controller).

Correct operation of the JTAG interface requires configuration of a group of system control pins as demonstrated in Figure 61. Care must be taken to ensure that these pins are maintained at a valid deasserted state under normal operating conditions because most have asynchronous behavior and spurious assertion, which give unpredictable results.

Refer to the *PCI 2.2 Specification*, for all pull-ups required for PCI.

22.9 JTAG Configuration Signals

Boundary scan testing is enabled through the JTAG interface signals. The $\overline{\text{TRST}}$ signal is optional in IEEE 1149.1, but is provided on any Freescale devices that are built on Power Architecture technology. The device requires $\overline{\text{TRST}}$ to be asserted during reset conditions to ensure the JTAG boundary logic does not interfere with normal chip operation. While it is possible to force the TAP controller to the reset state using only the TCK and TMS signals, systems generally assert $\overline{\text{TRST}}$ during power-on reset. Because the JTAG interface is also used for accessing the common on-chip processor (COP) function, simply tying $\overline{\text{TRST}}$ to $\overline{\text{PORESET}}$ is not practical.

23.1 Part Numbers Fully Addressed by this Document

This table provides the Freescale part numbering nomenclature for the MPC8313E. Note that the individual part numbers correspond to a maximum processor core frequency. For available frequencies, contact your local Freescale sales office. In addition to the processor frequency, the part numbering scheme also includes an application modifier which may specify special application conditions. Each part number also contains a revision code which refers to the die mask revision number.

Table 72. Part Numbering Nomenclature

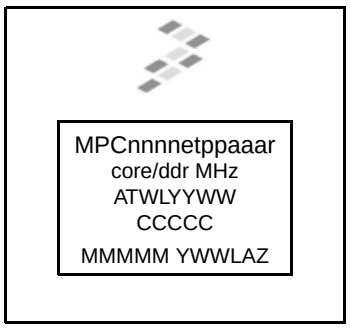
MPC	*nnnn*	*e*	*t*	*pp*	*aa*	*a*	*x*
Product Code	**Part Identifier**	**Encryption Acceleration**	**Temperature Range [3]**	**Package [1, 4]**	**e300 core Frequency [2]**	**DDR Frequency**	**Revision Level**
MPC	8313	Blank = Not included E = included	Blank = 0° to 105°C C= –40° to 105°C	ZQ = PB TEPBGAII VR = PB free TEPBGAII	AD = 266 MHz AF = 333 MHz AG = 400 MHz	D = 266 MHz F = 333 MHz	Blank = 1.0 A = 2.0 B = 2.1 C = 2.2

Note:

1. See Section 19, “Package and Pin Listings,” for more information on available package types.
2. Processor core frequencies supported by parts addressed by this specification only. Not all parts described in this specification support all core frequencies. Additionally, parts addressed by Part Number Specifications may support other maximum core frequencies.
3. Contact local Freescale office on availability of parts with °C temperature range.
4. ZQ package was available for Rev 1.0. For Rev 2.x, only VR package is available.

23.2 Part Marking

Parts are marked as shown in this figure.



TePBGA

Notes:
MPCnnnnetppaar is the orderable part number.
ATWLYYWW is the standard assembly, test, year, and work week codes.
CCCCC is the country code.
MMMMM is the mask number.

Figure 62. Part Marking for TEPBGAII Device